# 350 mA Very Low I<sub>q</sub> Low Dropout Linear Regulator with Reset and Reset Delay

The NCV8675 is a precision 5.0 V and 3.3 V fixed output, low dropout integrated voltage regulator with an output current capability of 350 mA. Careful management of light load current consumption, combined with a low leakage process, achieve a typical quiescent ground current of 34 µA.

NCV8675 is pin for pin compatible with NCV4275 and it could replace this part when very low quiescent current is required.

The output voltage is accurate within  $\pm 2.0\%$  for D<sup>2</sup>PAK-5 package and ±2.5% for DPAK-5 package, and maximum dropout voltage is 600 mV at full rated load current.

It is internally protected against input transients, input supply reversal, output overcurrent faults, and excess die temperature. No external components are required to enable these features.

#### **Features**

- 5 V and 3.3 V Fixed Output (2.5 V Version Available Upon Request)
- ±2.0% or ±2.5% Output Accuracy, Over Full Temperature Range
- 34 μA Typical Quiescent Current at I<sub>out</sub> = 100 μA, 50 μA Maximum up to 85°C
- 600 mV Maximum Dropout Voltage at 350 mA Load Current
- Wide Input Voltage Operating Range of 4.5 V to 45 V
- Internal Fault Protection
  - → -42 V Reverse Voltage
  - ◆ Short Circuit/Overcurrent
  - ◆ Thermal Overload
- AEC-Q100 Qualified
- EMC Compliant
- NCV Prefix for Automotive and Other Applications Requiring Site and Control Changes
- These are Pb-Free Devices

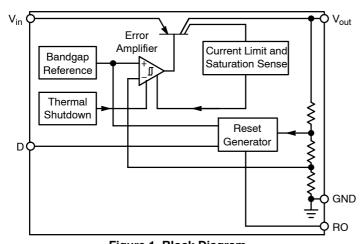


Figure 1. Block Diagram



# ON Semiconductor®

http://onsemi.com

# **MARKING DIAGRAMS**



DPAK-5 **DT SUFFIX** CASE 175AA





D<sup>2</sup>PAK-5 **DS SUFFIX** CASE 936A



Pin 1. Vin

2. RO

Tab, 3. GND\*

4. D

5. Vout

\* Tab is connected to Pin 3 on all packages

= 50 (5.0 V Version)

33 (3.3 V Version)

= Assembly Location

= Wafer Lot WL.I = Year

WW = Work Week

= Pb-Free Package

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 14 of this data sheet.

# **PIN DESCRIPTIONS**

Symbol	Function
V <sub>in</sub>	Unregulated Input Voltage; 4.5 V to 45 V; Battery Input Voltage. Bypass to GND with a Ceramic Capacitor.
RO	Reset Output; Open Collector Active Reset (Accurate when V <sub>in</sub> > 1.0 V)
GND	Ground; Pin 3 Internally Connected to Tab
D	Reset Delay; Timing Capacitor to GND for Reset Delay Function
V <sub>out</sub>	Output; 350 mA. 22 $\mu$ F, ESR < 9 $\Omega$

#### **MAXIMUM RATINGS**

Pin Symbol, Parameter	Symbol	Min	Max	Unit
Input Voltage	V <sub>in</sub>	-42	45	V
Output Voltage	V <sub>out</sub>	-0.3	16	V
Reset Output Voltage	V <sub>RO</sub>	-0.3	25	V
Reset Output Current	I <sub>RO</sub>	-5.0	5.0	mA
Reset Delay Voltage	V <sub>D</sub>	-0.3	7.0	V
Reset Delay Current	I <sub>D</sub>	-2.0	2.0	mA
Storage Temperature	T <sub>Stg</sub>	-55	+150	°C
ESD Capability -Human Body Model -Machine Model	- -	4 200		kV V
Storage Temperature	T <sub>Stg</sub>	-55	+150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

# **OPERATING RANGE**

Pin Symbol, Parameter	Symbol	Min	Max	Unit
Input Voltage Operating Range	V <sub>in</sub>	4.5	45	V
Junction Temperature	$T_J$	-40	150	°C

#### THERMAL RESISTANCE

Parameter			Min	Max	Unit
Junction Ambient	D <sup>2</sup> PAK	R <sub>thja</sub>		82.1	OCAM.
Junction Case	D <sup>2</sup> PAK	R <sub>thjc</sub>		4.3	°C/W
Junction Ambient	DPAK	R <sub>thja</sub>		112.2	°C/W
Junction Case	DPAK	R <sub>thjc</sub>		4.3	30/00

<sup>1. 1</sup> oz., 100 mm<sup>2</sup> copper area.

# Pb SOLDERING TEMPERATURE AND MSL

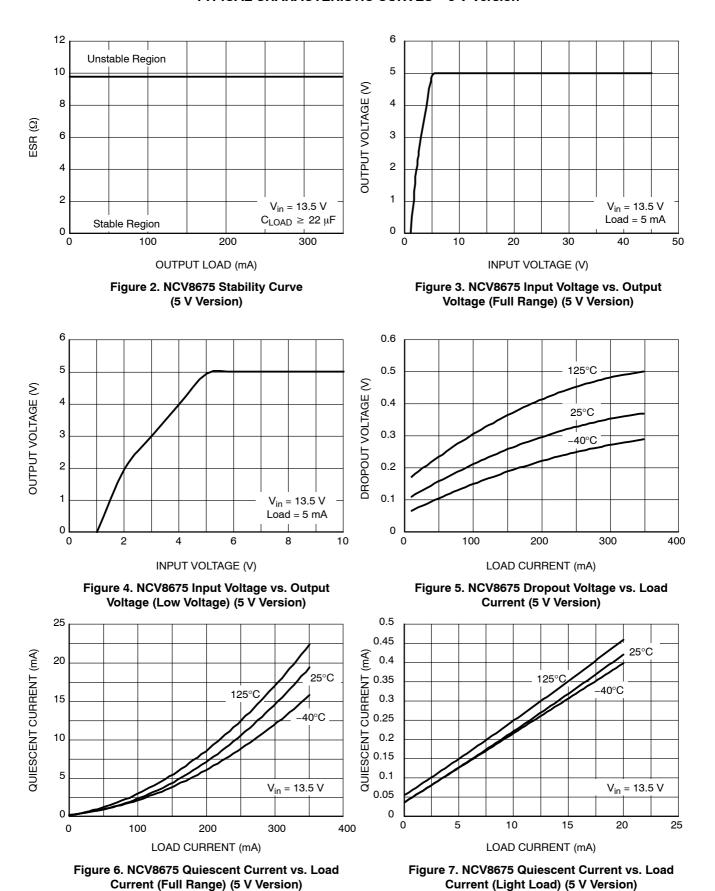
Parameter	Symbol	Min	Max	Unit
Lead Temperature Soldering Reflow (SMD styles only), Pb-Free (Note 2)	T <sub>sld</sub>		265 pk	°C
Moisture Sensitivity Level	MSL	1		-

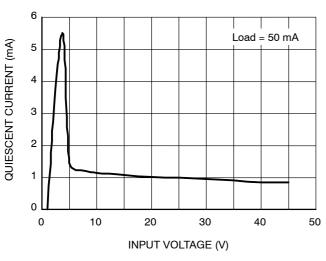
<sup>2.</sup> Pb-Free,  $60 \ \text{sec} - 150 \ \text{sec}$  above  $217^{\circ}\text{C}$ ,  $40 \ \text{sec}$  maximum at peak.

# **ELECTRICAL CHARACTERISTICS** $V_{in}$ = 13.5 V, $T_J$ = -40°C to +150°C, unless otherwise specified

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
OUTPUT			•	•	•	
Output Voltage D <sup>2</sup> PAK 5.0 V Version DPAK	$V_{out}$	0.1 mA $\leq$ I <sub>out</sub> $\leq$ 350 mA (Note 3) 6.0 V $\leq$ V <sub>in</sub> $\leq$ 16 V	4.900 4.875	5.000 5.000	5.100 5.125	V
Output Voltage D <sup>2</sup> PAK 3.3 V Version DPAK	V <sub>out</sub>	0.1 mA $\leq$ I <sub>out</sub> $\leq$ 350 mA (Note 3) 4.5 V $\leq$ V <sub>in</sub> $\leq$ 16 V	3.234 3.217	3.300 3.300	3.366 3.383	V
Output Voltage D <sup>2</sup> PAK 5.0 V Version DPAK	V <sub>out</sub>	0.1 mA $\leq$ I <sub>out</sub> $\leq$ 200 mA (Note 3) 6.0 V $\leq$ V <sub>in</sub> $\leq$ 40 V	4.900 4.875	5.000 5.000	5.100 5.125	V
Output Voltage D <sup>2</sup> PAK 3.3 V Version DPAK	V <sub>out</sub>	0.1 mA $\leq$ I <sub>out</sub> $\leq$ 200 mA (Note 3) 4.5 V $\leq$ V <sub>in</sub> $\leq$ 40 V	3.234 3.217	3.300 3.300	3.366 3.383	V
Line Regulation	ΔV <sub>out</sub> Versus V <sub>in</sub>	l <sub>out</sub> = 5 mA 6.0 V ≤ V <sub>in</sub> ≤ 28 V	-25	5	+25	mV
Load Regulation	ΔV <sub>out</sub> Versus. I <sub>out</sub>	1.0 mA ≤ I <sub>out</sub> ≤ 350 mA (Note 3)	-40	5	+40	mV
Dropout Voltage 5.0 V Version	V <sub>in</sub> – V <sub>out</sub>	I <sub>out</sub> = 200 mA (Notes 3 and 4) I <sub>out</sub> = 350 mA (Notes 3 and 4)	- -	215 310	500 600	mV
Quiescent Current	Iq	$\begin{split} I_{out} &\leq 100~\mu\text{A} \\ T_J &= 25^\circ\text{C} \\ T_J &= -40^\circ\text{C to } +85^\circ\text{C} \\ T_J &= 125^\circ\text{C} \end{split}$		34 34 54	45 50 60	μΑ
Active Ground Current	I <sub>G (ON)</sub>	I <sub>out</sub> = 50 mA (Note 3) I <sub>out</sub> = 350 mA (Note 3)		1.8 20	3.5 40	mA
Power Supply Rejection	P <sub>SRR</sub>	V <sub>RIPPLE</sub> = 0.5 V <sub>PP</sub> , F = 100 Hz		70		%/V
Output Capacitor for Stability 5.0 V Version 3.3 V Version	C <sub>out</sub> ESR C <sub>out</sub> ESR	I <sub>out</sub> = 0.1 mA to 350 mA	22 22		9 7	μF Ω μF Ω
RESET TIMING D AND OUTPUT R	)			•	•	•
Reset Switching Threshold	V <sub>out</sub> , r <sub>t</sub>	5.0 V Version 3.3 V Version	4.50 2.97	4.65 3.069	4.80 3.168	V
Reset Output Low Voltage	V <sub>ROL</sub>	R <sub>Ext</sub> > 5.0k, V <sub>out</sub> > 1.0V	-	0.20	0.40	V
Reset Output Leakage Current	I <sub>ROH</sub>	V <sub>ROH</sub> = 5.0 V V <sub>ROH</sub> = 3.3 V	_ _	0 0	10 10	μΑ
Reset Charging Current	I <sub>D,C</sub>	V <sub>D</sub> = 1.0 V	2.0	4.0	6.5	μΑ
Upper Timing Threshold	V <sub>DU</sub>	-	1.2	1.3	1.4	V
Lower Timing Threshold	$V_{LU}$			1.24		V
Reset Delay Time 5.0 V Version 3.3 V Version	t <sub>rd</sub>	C <sub>D</sub> = 47 nF	10 10	16 16	22 24	ms
Reset Reaction Time	t <sub>rr</sub>	C <sub>D</sub> = 47 nF		1.5	4.0	μs
PROTECTION						
Current Limit	I <sub>out(LIM)</sub>	V <sub>out</sub> = 4.5 V (5.0 V Version) V <sub>out</sub> = 3.0 V (3.3 V Version)	350 350			mA
Short Circuit Current Limit	I <sub>out(SC)</sub>	V <sub>out</sub> = 0 V (Note 3)	100	600		mA
Thermal Shutdown Threshold	T <sub>TSD</sub>	(Note 5)	150		200	°C

Use pulse loading to limit power dissipation.
 Dropout voltage = (V<sub>in</sub> - V<sub>out</sub>), measured when the output voltage has dropped 100 mV relative to the nominal value obtained with V<sub>in</sub> = 13.5 V.
Not tested in production. Limits are guaranteed by design.

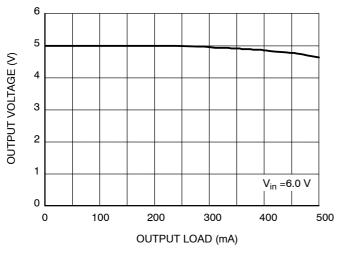




0.07 0.06 QUIESCENT CURRENT (mA) 0.05 0.04 0.03 0.02  $V_{in} = 13.5 \ V$ 0.01 Load = 100  $\mu$ A -50 0 50 100 150 TEMPERATURE (°C)

Figure 8. NCV8675 Quiescent Current vs. Input Voltage (5 V Version)

Figure 9. NCV8675 Quiescent Current vs. Temperature (5 V Version)



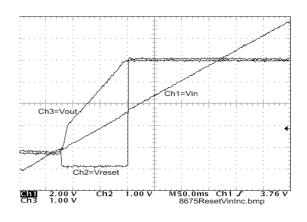
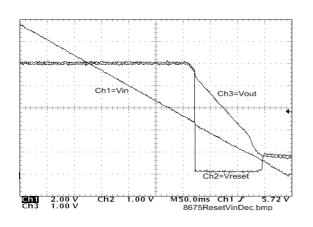


Figure 10. NCV8675 Output Voltage vs. Output Load (5 V Version)

Figure 11. Reset vs. Output Voltage (V<sub>in</sub> Rising) (5 V Version)



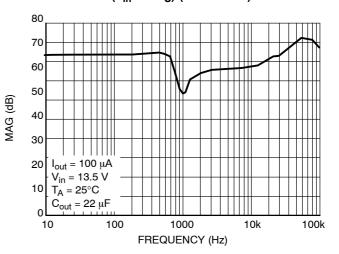


Figure 12. Reset vs. Output Voltage (V<sub>in</sub> Falling) (5 V Version)

Figure 13. Power Supply Rejection Ratio (5 V Version)

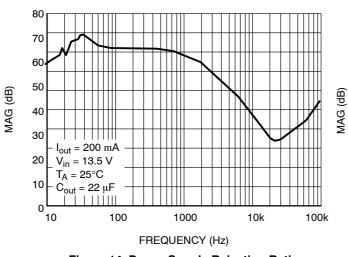


Figure 14. Power Supply Rejection Ratio (5 V Version)

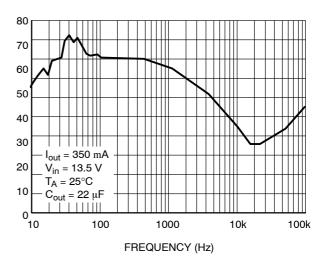


Figure 15. Power Supply Rejection Ratio (5 V Version)

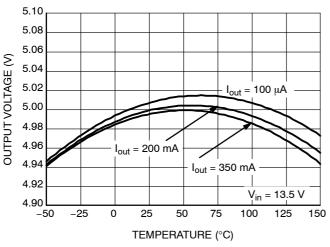


Figure 16. NCV8675 Output Voltage vs. Temperature (5 V Version)

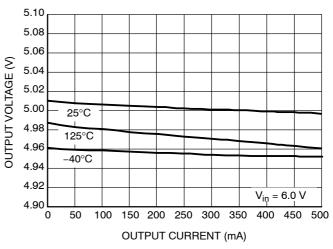


Figure 17. NCV8675 Output Voltage vs. Output Load (5 V Version)

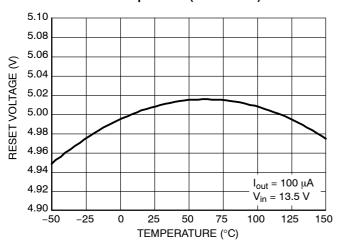


Figure 18. NCV8675 Reset Voltage vs. Temperature (5 V Version)

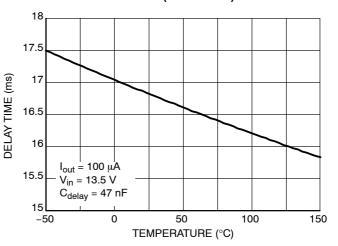


Figure 19. NCV8675 Reset Delay Time vs. Temperature (5 V Version)

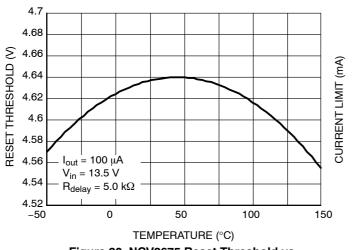


Figure 20. NCV8675 Reset Threshold vs. Temperature (5 V Version)

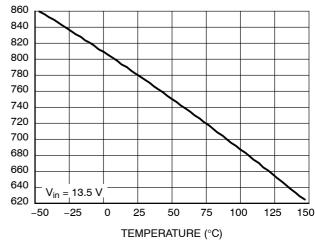


Figure 21. NCV8675 Current Limit Threshold vs. Temperature (5 V Version)

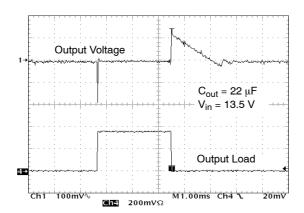


Figure 22. NCV8675 100 μA – 350 mA Load Transient (5 V Version)

#### TYPICAL CHARACTERISTIC CURVES - 3.3 V Version

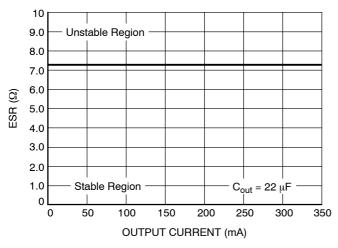


Figure 23. ESR Stability vs. Output Current (3.3 V Version)

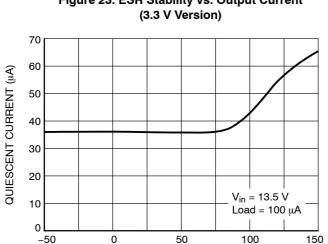


Figure 25. Quiescent Current vs. Temperature (3.3 V Version)

50

TEMPERATURE (°C)

-50

0

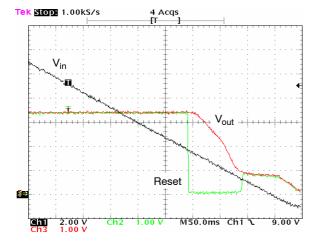


Figure 27. Reset vs. Output Voltage (V<sub>in</sub> Falling) (3.3 V Version)

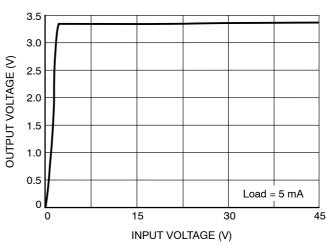


Figure 24. Input Voltage vs. Output Voltage (3.3 V Version)

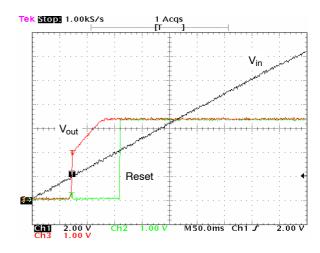


Figure 26. Reset vs. Output Voltage (V<sub>in</sub> Rising) (3.3 V Version)

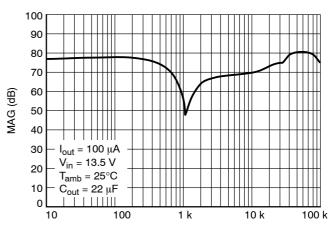


Figure 28. Power Supply Rejection Ratio (3.3 V Version)

150

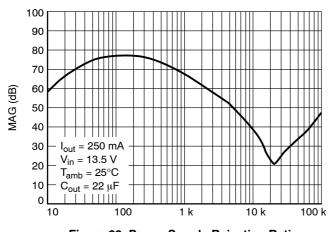


Figure 29. Power Supply Rejection Ratio (3.3 V Version)

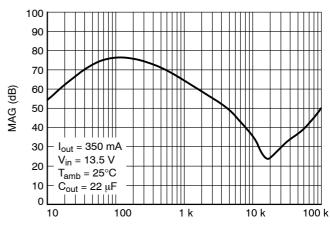


Figure 30. Power Supply Rejection Ratio (3.3 V Version)

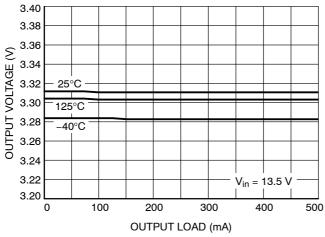


Figure 31. Output Voltage vs. Output Load (3.3 V Version)

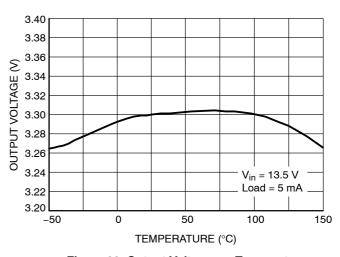


Figure 32. Output Voltage vs. Temperature (3.3 V Version)

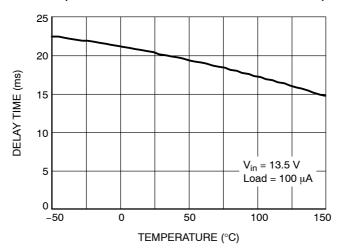


Figure 33. Reset Delay Time vs. Temperature (3.3 V Version)

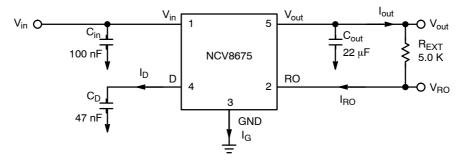


Figure 34. Application Circuits

# **Circuit Description**

The NCV8675 is an integrated low dropout regulator that provides 5.0 V 350 mA, or 3.3 V 350 mA protected output and a signal for power on reset. The regulation is provided by a PNP pass transistor controlled by an error amplifier with a bandgap reference, which gives it the lowest possible drop out voltage and best possible temperature stability. The output current capability is 350 mA, and the base drive quiescent current is controlled to prevent over saturation when the input voltage is low or when the output is overloaded. The regulator is protected by both current limit and thermal shutdown. Thermal shutdown occurs above 150°C to protect the IC during overloads and extreme ambient temperatures. The delay time for the reset output is adjustable by selection of the timing capacitor. See Figure 34, Test Circuit, for circuit element nomenclature illustration.

# Regulator

The error amplifier compares the reference voltage to a sample of the output voltage ( $V_{out}$ ) and drives the base of a PNP series pass transistor by a buffer. The reference is a bandgap design to give it a temperature–stable output. Saturation control of the PNP is a function of the load current and input voltage. Oversaturation of the output power device is prevented, and quiescent current in the ground pin is minimized.

#### **Regulator Stability Considerations**

The input capacitor ( $C_{in}$ ) is necessary to stabilize the input impedance to avoid voltage line influences. The output capacitor helps determine three main characteristics of a linear regulator: startup delay, load transient response and loop stability. The capacitor value and type should be based on cost, availability, size and temperature constraints. Ceramic, tantalum, or electrolytic capacitors of 22  $\mu$ F, or greater, are stable with very low ESR values. Refer to

Figure 2 for specific ESR ratings. The aluminum electrolytic capacitor is the least expensive solution, but, if the circuit operates at low temperatures ( $-25^{\circ}$ C to  $-40^{\circ}$ C), both the capacitance and ESR of the capacitor will vary considerably. The capacitor manufacturer's data sheet usually provides this information. The value for the output capacitor  $C_{out}$  shown in Figure 13, Test Circuit, should work for most applications; however, it is not necessarily the optimized solution.

#### **Reset Output**

The reset output is used as the power on indicator to the microcontroller. This signal indicates when the output voltage is suitable for reliable operation of the controller. It pulls low when the output is not considered to be ready. RO is pulled up to  $V_{out}$  by an external resistor, typically 5.0 k $\Omega$ in value. The input and output conditions that control the Reset Output and the relative timing are illustrated in Figure 35, Reset Timing. Output voltage regulation must be maintained for the delay time before the reset output signals a valid condition. The delay for the reset output is defined as the amount of time it takes the timing capacitor on the delay pin to charge from a residual voltage of 0 V to the upper timing threshold voltage V<sub>DU</sub> of 1.3 V. The charging current for this is I<sub>D</sub> of 4 μA and D pin voltage in steady state is typically 2.4 V. By using typical IC parameters with a 47 nF capacitor on the D Pin, the following time delay is derived:

$$\begin{split} t_{RD} &= \, C_D^{\,\,*} \, V_{DU}^{} / I_D^{} \\ t_{RD} &= \, 47 \; nF \,^* \, (1.3 \; V) / 4 \; \mu A \, = \, 15.3 \; ms \end{split}$$

Other time delays can be obtained by changing the  $C_D$  capacitor value. The Delay Time can be reduced by decreasing the capacitance of  $C_D$ . Using the formula above, Delay can be reduced as desired. Leaving the Delay Pin open is not desirable as it can result in unwanted signals being coupled onto the pin.

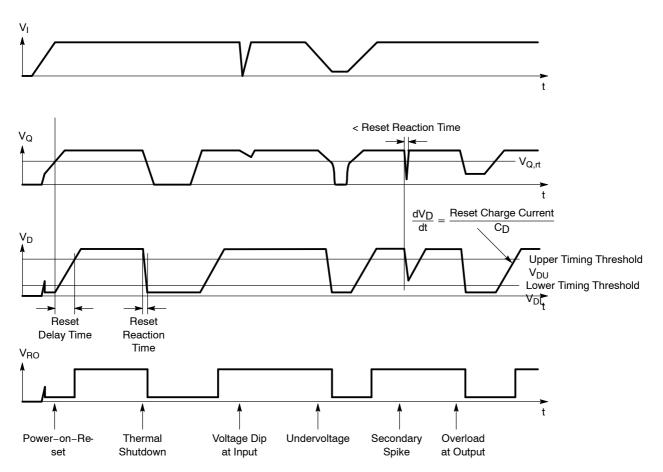


Figure 35. Reset Timing

# Calculating Power Dissipation in a Single Output Linear Regulator

The maximum power dissipation for a single output regulator (Figure 36) is:

$$PD(max) = [Vin(max) - Vout(min)] Iout(max) + VI(max)Iq$$
(1)

where

 $\begin{array}{lll} V_{in(max)} & \text{is the maximum input voltage,} \\ V_{out(min)} & \text{is the minimum output voltage,} \\ I_{out(max)} & \text{is the minimum output current for the application,} \\ I_q & \text{is the quiescent current the regulator} \\ & \text{consumes at } I_{O(max)}. \end{array}$ 

Once the value of  $P_{D(max)}$  is known, the maximum permissible value of  $R_{\theta JA}$  can be calculated:

$$R_{\theta JA} = \frac{150^{\circ}C - T_{A}}{P_{D}}$$
 (2)

The value of  $R_{\theta JA}$  can then be compared with those in the package section of the data sheet. Those packages with  $R_{\theta JA}$ 's less than the calculated value in Equation 2 will keep the die temperature below 150°C.

In some cases, none of the packages will be sufficient to dissipate the heat generated by the IC, and an external heatsink will be required.

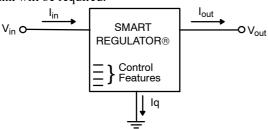


Figure 36. Single Output Regulator with Key Performance Parameters Labeled

#### **Heatsinks**

A heatsink effectively increases the surface area of the package to improve the flow of heat away from the IC and into the surrounding air.

Each material in the heat flow path between the IC and the outside environment will have a thermal resistance. Like series electrical resistances, these resistances are summed to determine the value of  $R_{\theta JA}$ :

$$R_{\theta}JA = R_{\theta}JC + R_{\theta}CS + R_{\theta}SA \tag{3}$$

where

 $R_{ ext{OJC}}$  is the junction-to-case thermal resistance,  $R_{ ext{OCS}}$  is the case-to-heatsink thermal resistance, is the heatsink-to-ambient thermal resistance.

 $R_{\theta JC}$  appears in the package section of the data sheet. Like  $R_{\theta JA}$ , it too is a function of package type.  $R_{\theta CS}$  and  $R_{\theta SA}$  are functions of the package type, heatsink and the interface between them. These values appear in heatsink data sheets of heatsink manufacturers.

Thermal, mounting, and heatsinking considerations are discussed in the ON Semiconductor application note AN1040/D.

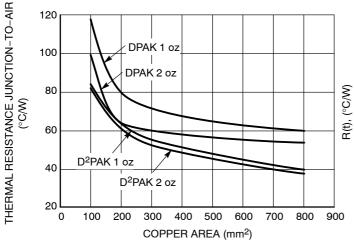


Figure 37. JA vs. Copper Spreader Area

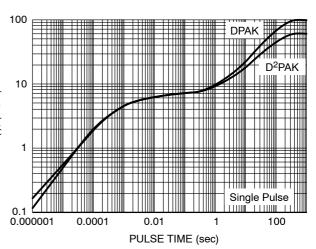


Figure 38. NCV8675 @ PCB Cu Area 100 mm<sup>2</sup> PCB Cu thk 1 oz

#### **EMC-Characteristics: Conducted Susceptibility**

All EMC-Characteristics are based on limited samples and no part of production test according to 47A/658/CD IEC62132-4 (direct Power Injection).

#### **Test Conditions**

Supply Voltage  $V_{in} = 12 \text{ V}$ 

Temperature  $T_A = 23^{\circ}C + -5^{\circ}C$ 

Load  $R_L = 100 \Omega$ 

#### **Direct power Injection**

33d Bm (Note 1) forward power CW for global pin (Note 2) 17 dBm (Note 1) forward power CW for local pin (Note 3)

#### Acceptance Criteria

Amplitude Dev. max 4% of Output Voltage Reset outputs remain in correct state + -1 V

- 1. dBm means dB milli-Watts,  $P_{(dBm)} = 10 \log (P_{(mW)})$
- 2. A global pin carries a signal or power which enters or leaves the application board
- 3. A local pin carries a signal or power which does not leave the application board. It remains on the application board as a signal between two components

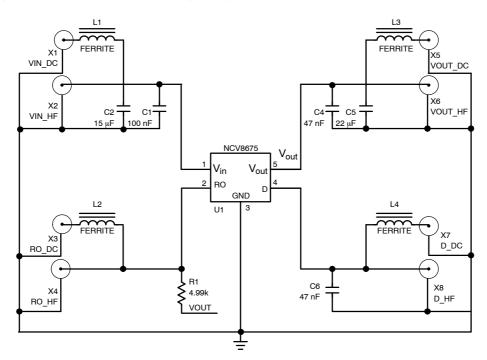
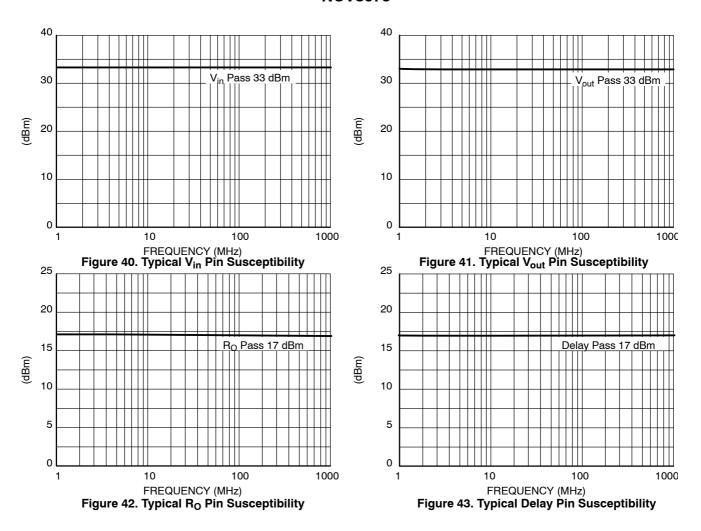


Figure 39. Test Circuit



## **ORDERING INFORMATION**

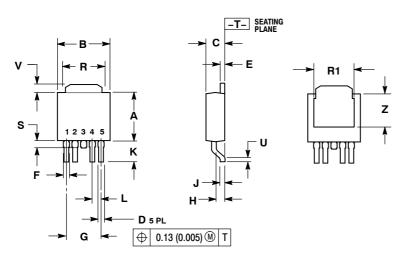
Device	Output Voltage	Package	Shipping <sup>†</sup>
NCV8675DS50G		D <sup>2</sup> PAK	50 Units / Rail
NCV8675DS50R4G	5.0 V	(Pb-Free)	800 / Tape & Reel
NCV8675DT50RKG		DPAK (Pb-Free)	2500 / Tape & Reel
NCV8675DS33G		D <sup>2</sup> PAK	50 Units / Rail
NCV8675DS33R4G	3.3 V	(Pb-Free)	800 / Tape & Reel
NCV8675DT33RKG		DPAK (Pb-Free)	2500 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **PACKAGE DIMENSIONS**

# DPAK-5, CENTER LEAD CROP

CASE 175AA-01 **ISSUE A** 



#### NOTES:

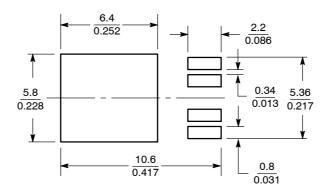
- OTES.

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.22
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.020	0.028	0.51	0.71
Е	0.018	0.023	0.46	0.58
F	0.024	0.032	0.61	0.81
G	0.180	BSC	4.56	BSC
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.045	BSC	1.14	BSC
R	0.170	0.190	4.32	4.83
R1	0.185	0.210	4.70	5.33
S	0.025	0.040	0.63	1.01
υ	0.020		0.51	
٧	0.035	0.050	0.89	1.27
z	0.155	0.170	3.93	4.32

# **SOLDERING FOOTPRINT\***

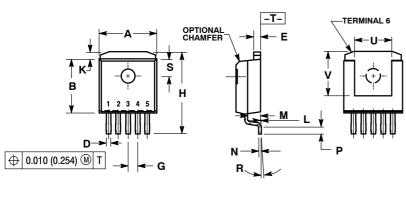


SCALE 4:1  $\left(\frac{\text{mm}}{\text{inches}}\right)$ 

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

#### D<sup>2</sup>PAK-5 CASE 936A-02 **ISSUE C**



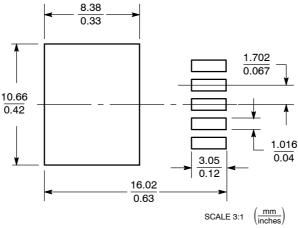


#### **SOLDERING FOOTPRINT\***

#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
- TAB CONTOUR OPTIONAL WITHIN DIMENSIONS A AND K.
- DIMENSIONS U AND V ESTABLISH A MINIMUM MOUNTING SURFACE FOR TERMINAL 6.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.025 (0.635) MAXIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.386	0.403	9.804	10.236
В	0.356	0.368	9.042	9.347
С	0.170	0.180	4.318	4.572
D	0.026	0.036	0.660	0.914
E	0.045	0.055	1.143	1.397
G	0.067	BSC	1.702	BSC
Н	0.539	0.579	13.691	14.707
K	0.050	REF	1.270 REF	
L	0.000	0.010	0.000	0.254
М	0.088	0.102	2.235	2.591
N	0.018	0.026	0.457	0.660
P	0.058	0.078	1.473	1.981
R	5° REF		5° REF	
S	0.116 REF		2.946 REF	
U	0.200 MIN		5.080 MIN	
V	0.250 MIN		6.350	MIN



#### 5-LEAD D<sup>2</sup>PAK

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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